

# BIPOLAR ANALOG INTEGRATED CIRCUIT

# $\mu$ PC8116GR

## 500 MHz, AM/ASK RECEIVER IC

### DESCRIPTION

$\mu$ PC8116GR is a Silicon monolithic IC designed for AM/ASK receiver. This IC consists of mixer, oscillator, IF amplifier, Limiter amplifier, OP Amp., and built in power save function and RSSI function.

The package is 20 pin SSOP (shrink small outline package) suitable for high-density surface mount.

### FEATURES

- Broadband operation :  $f_{RF} = 100$  to 500 MHz
- Low power dissipation : 12.3 mW at  $V_{CC} = 3$  V, 23.5 mW at  $V_{CC} = 5$  V
- On-chip power save function :  $I_{P/S} \leq 1 \mu A$
- Packaged in 20 pin SSOP suitable for high-density surface mount.

### ORDERING INFORMATION

PART NUMBER	PACKAGE	PACKAGE STYLE
$\mu$ PC8116GR-E1	20 pins plastic SSOP (225mil)	Embossed tape 12 mm wide. 2.5 k/REEL Pin 1 indicates pull-out direction of tape

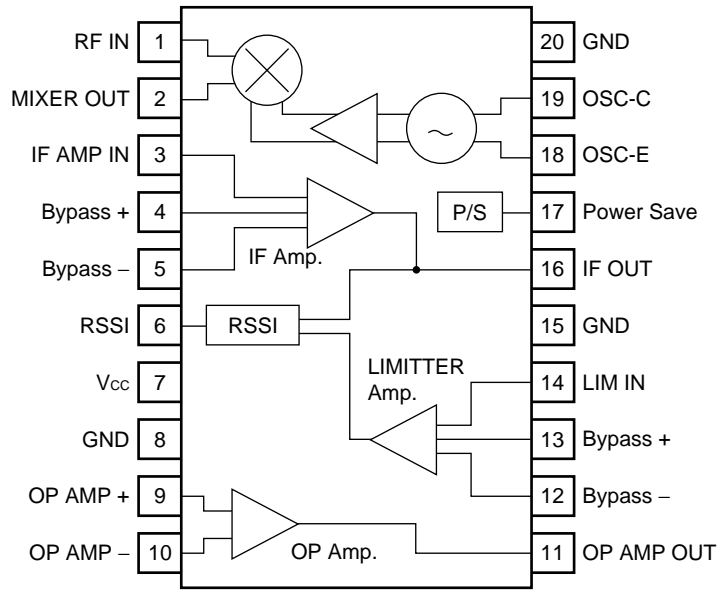
\*: For evaluation sample order, please contact your local NEC office. (Order name:  $\mu$ PC8116GR)

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

**Caution electro-static sensitive device**

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

INTERNAL BLOCK DIAGRAM AND PIN CONFIGURATION (Top View)



**PIN EXPLANATION**

Pin No	SYMBOL	Pin Volt TYP. (V)	Function and Explanation	Equivalent circuit
1	MIX IN	1.95	RF signal input pin.	
2	MIX OUT	2.1	Output pin of Mixer. This pin is assigned for emitter follower output with Low-impedance	
3	IF IN	2.38	IF signal input pin.	
4	BYPASS + (IF)	2.38	Bypass pin for IF Amplifier. Capacitor for filter should be connected between 4 pin and 5 pin.	
5	BYPASS - (IF)	2.38		
6	RSSI OUT	0.9	RSSI signal output pin.	
7	Vcc	3.0	Power supply pin.	
8	GND	0.0	Ground pin for OP-Amp.	
9	OP Amp +	2.1	Input pin of OP-Amp. In case of single input, 9 pin or 10 pin should be grounded through capacitor.	
10	OP Amp -	2.1		

Pin No	SYMBOL	Pin Volt TYP. (V)	Function and Explanation	Equivalent circuit						
11	OP Amp OUT	0.77	Output pin of OP-Amp. This pin is assigned for emitter follower output.							
12	BYPASS -	2.38	Bypass pin for OP-Amp. Capacitor for filter should be connected between 12 pin and 13 pin.							
13	BYPASS +	2.38								
14	LIM IN	2.38			Input pin of Limitter Amplifier.					
15	GND	0.0	Ground pin for Limitter Amp., RSSI, and regulator.							
16	IF OUT	1.55	IF signal output pin. Generally, Crystal filter is connected between 16 pin and 14 pin.							
17	Power Save	0 to 3	Power save control pin can be controlled ON/SLEEP state with bias as follows; <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>V<sub>PS</sub> (V)</th> <th>STATE</th> </tr> </thead> <tbody> <tr> <td>V<sub>CC</sub></td> <td>ON</td> </tr> <tr> <td>GND</td> <td>SLEEP</td> </tr> </tbody> </table>	V <sub>PS</sub> (V)	STATE	V <sub>CC</sub>	ON	GND	SLEEP	
V <sub>PS</sub> (V)	STATE									
V <sub>CC</sub>	ON									
GND	SLEEP									
18	OSC-E	1.31	Oscillator signal input pins. Oscillator circuit should be connected between 18 pin and 19 pin.							
19	OSC-C	3.0								
20	GND	0.0	Ground pin for MIXER, IF Amplifier, and Oscillator.							

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C unless otherwise specified)**

PARAMETER	SYMBOL	TEST CONDITION	RATING	UNIT
Supply Voltage	V <sub>CC</sub>		6.0	V
Power Dissipation	P <sub>D</sub>	T <sub>A</sub> = 85 °C *1	430	mW
Operation Temperature Range	T <sub>A</sub>		-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>		-55 to +150	°C

\*1 Mounted on 50 × 50 × 1.6 mm epoxy glass board.

**RECOMMENDED OPERATING RANGE**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V <sub>CC</sub>	2.7	3.0	5.5	V
Operation Temperature Range	T <sub>A</sub>	-40	+25	+85	°C

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, V<sub>CC</sub> = V<sub>p/s</sub> = 3 V)**

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Total Block						
Circuit Current	I <sub>CC</sub>	2.6	4.1	5.7	mA	no input signal
RSSI Sensitivity	RSSI <sub>sen</sub>	-	-95	-90	dBm	f <sub>RF</sub> = 315 MHz, f <sub>OSC</sub> = 304.3 MHz, P <sub>OSC</sub> = -10 dBm, ΔV <sub>RSSI</sub> ≥ 3 mV/dB *2
Powersave Current	I <sub>p/s</sub>	-	-	1.0	μA	17 pin = GND *2
Mixer Block						
RF Input Frequency Range	BW <sub>RF</sub>	100	-	500	MHz	f <sub>IF</sub> = 10.7 MHz, f <sub>RF</sub> > f <sub>OSC</sub> , -3 dB down *3
LO Input Frequency Range	BW <sub>LO</sub>	100	-	500	MHz	f <sub>IF</sub> = 10.7 MHz, f <sub>RF</sub> > f <sub>OSC</sub> , -3 dB down *3
Mixer Gain	G <sub>MIX</sub>	8	11	14	dB	f <sub>RF</sub> = 315 MHz, P <sub>RF</sub> = -50 dBm, f <sub>OSC</sub> = 304.3MHz, P <sub>OSC</sub> = -10 dBm, Input:LC matching *2
IF Amp Block						
IF Output Frequency Range	BW <sub>IF</sub>	0.3	-	15	MHz	P <sub>in</sub> = -80 dBm, -3dB down *3
OP Amp Block						
OP Amp Input Frequency Range	BW <sub>OP</sub>	1	-	-	MHz	P <sub>in</sub> = -50 dBm, -3dB down *3
OP Amp Gain	G <sub>OP</sub>	50	57	-	dB	f <sub>in</sub> = 200 kHz, P <sub>in</sub> = -50 dBm *3

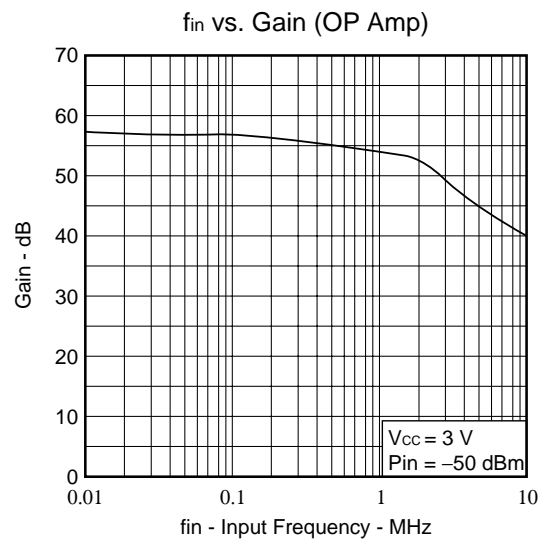
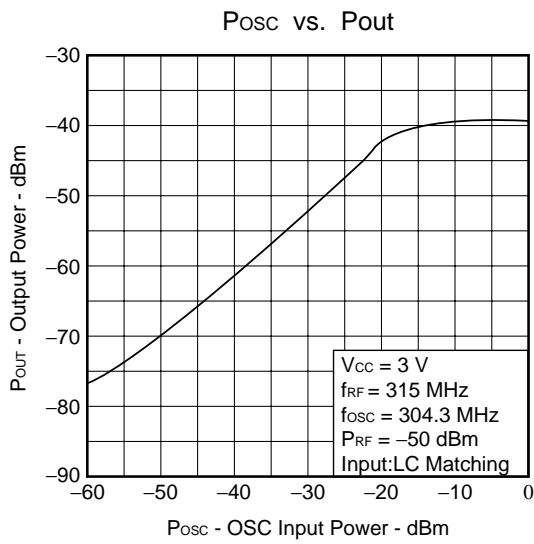
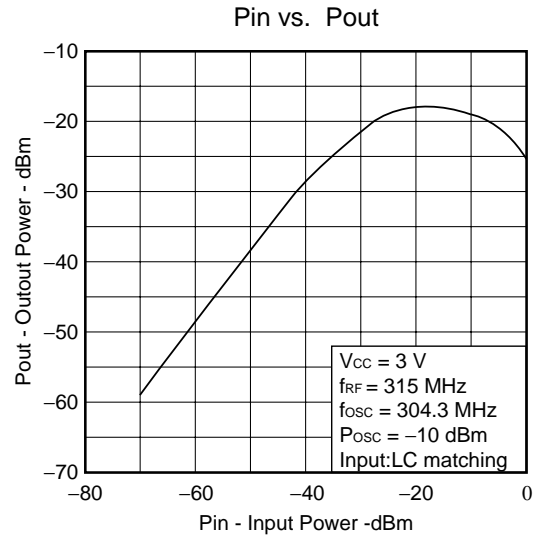
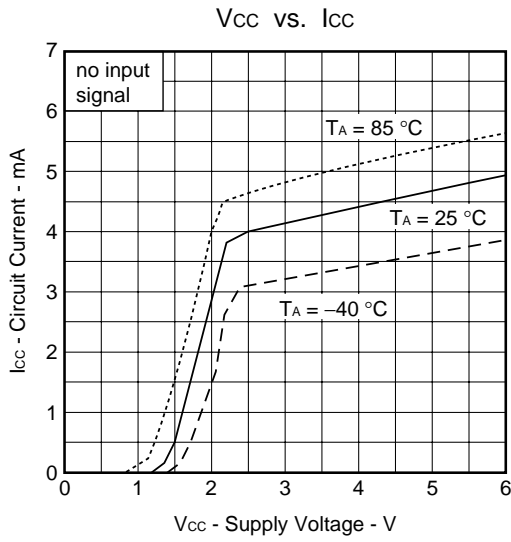
STANDARD CHARACTERISTICS (T<sub>A</sub> = 25 °C, V<sub>CC</sub> = V<sub>p/s</sub> = 3 V;<sup>\*2</sup>)

PARAMETER	Symbol	Value for reference	UNIT	TEST CONDITION
IF Amplifier Gain	G <sub>IF</sub>	55	dB	f <sub>in</sub> = 10.7 MHz, P <sub>in</sub> = -100 dBm, Input:LC Matching *2
RSSI Linearity	$\frac{\Delta RSSI}{\Delta P_{RF}}$	±3	dB	f <sub>RF</sub> = 315 MHz, f <sub>osc</sub> = 304.3 MHz, P <sub>osc</sub> = -10 dBm, P <sub>RF</sub> = -30 to -90 dBm *2
LO to RF Isolation	LO-RFiso	-50	dBm	f <sub>osc</sub> = 304.3 MHz/-10 dBm *2
RF to LO Isolation	RF-LOiso	-50	dBm	f <sub>RF</sub> = 315 MHz/-30 dBm *2

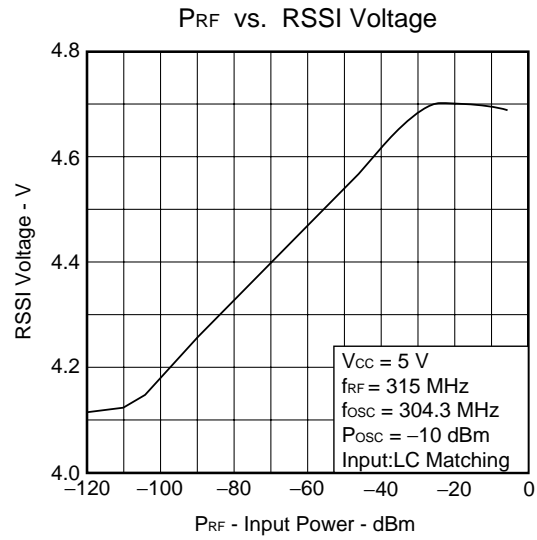
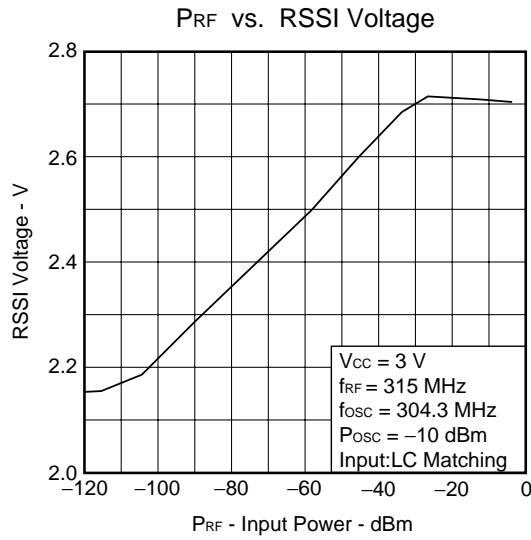
\*2 By Measurement Circuit 1

\*3 By Measurement Circuit 2

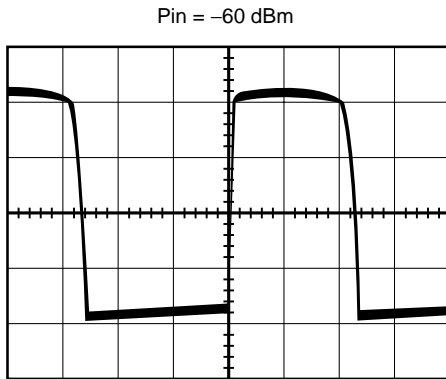
TYPICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ )



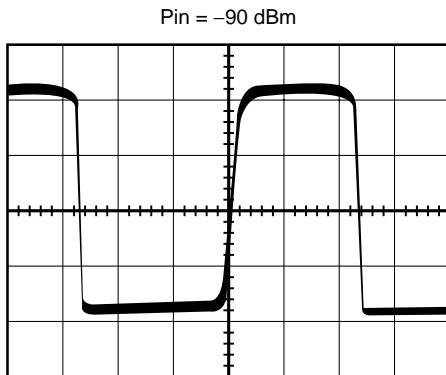
STANDARD CHARACTERISTICS (T<sub>A</sub> = 25 °C)



OP Amplifier Output



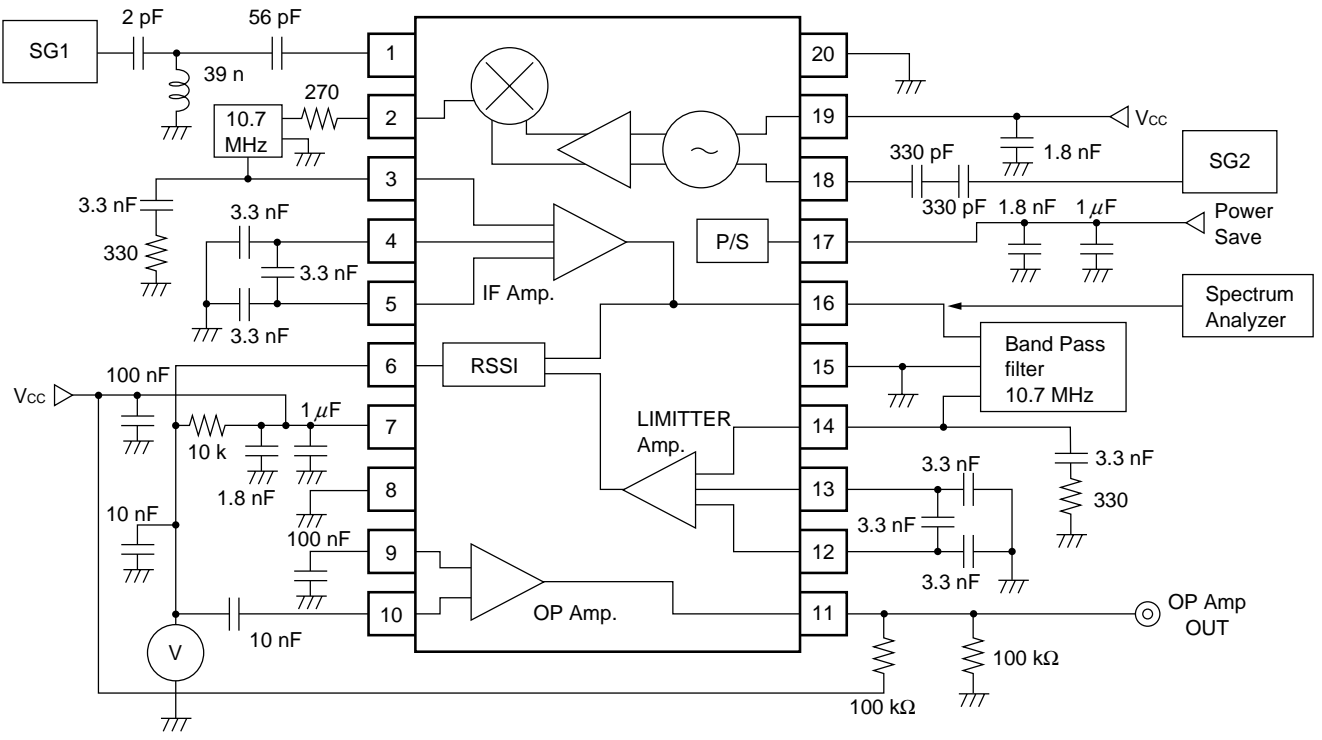
Test Conditions  
 f<sub>RF</sub> = 315 MHz  
 f<sub>OSC</sub> = 304.3 MHz  
 AM : 1 kHz, 90 %  
 V<sub>CC</sub> = 3 V



500 mV/DIV  
 200 μsec/DIV

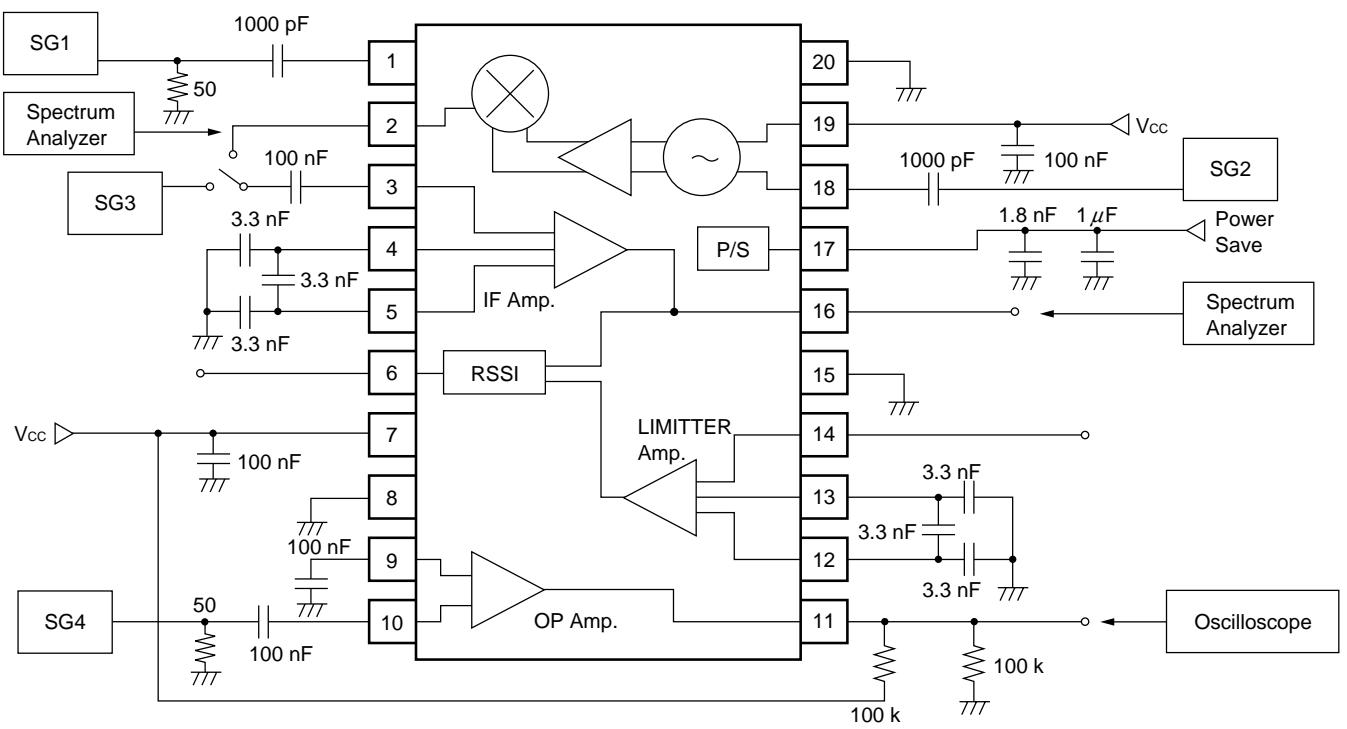


MEASUREMENT CIRCUIT1



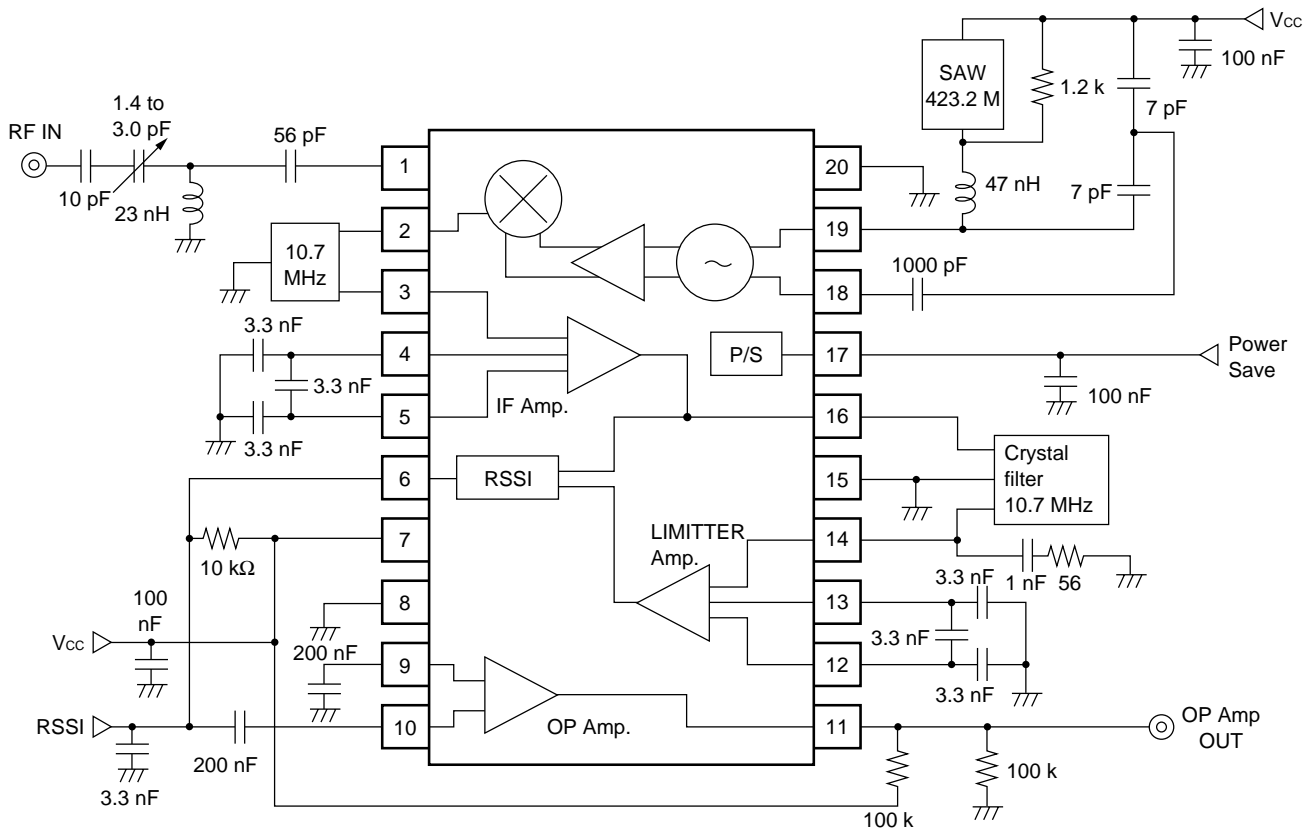
\*: •Measured by High-impedance Probe (1 MHz, 1.5pF)  
 •17 pin: GND, 11 pin: OPEN in case of measurement of powersave current

MEASUREMENT CIRCUIT2



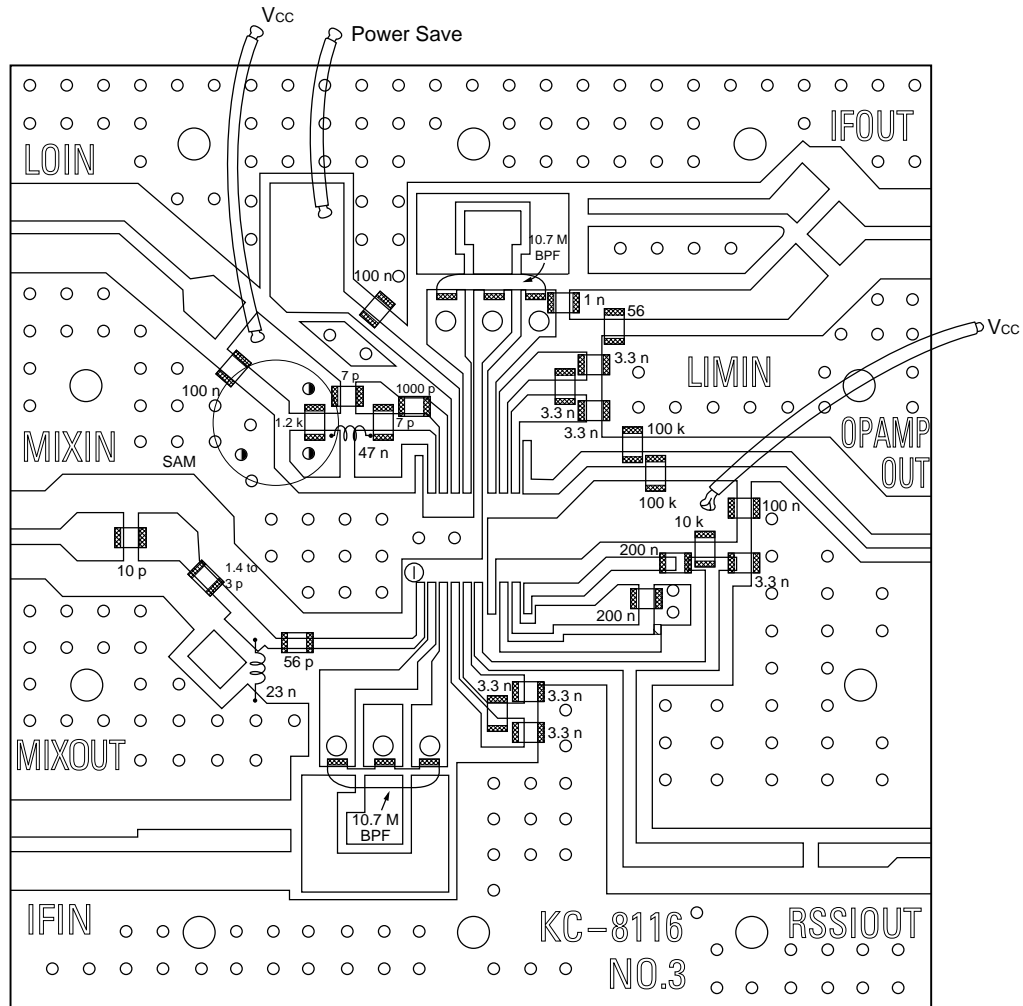
\*: •Measured by High-impedance Probe (1 MHz, 1.5pF)

APPLICATION CIRCUIT EXAMPLE (@f<sub>RF</sub> = 433.6 MHz)



The application circuits and their parameters are for reference only and are not intended for use in actual design-in's.

ILLUSTRATION OF THE APPLICATION CIRCUIT ASSEMBLED ON EVALUATION BOARD

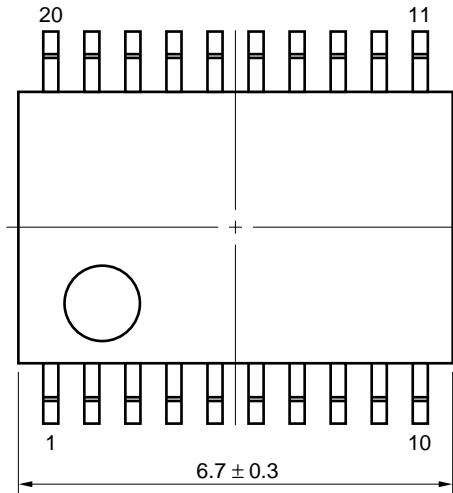


Notes

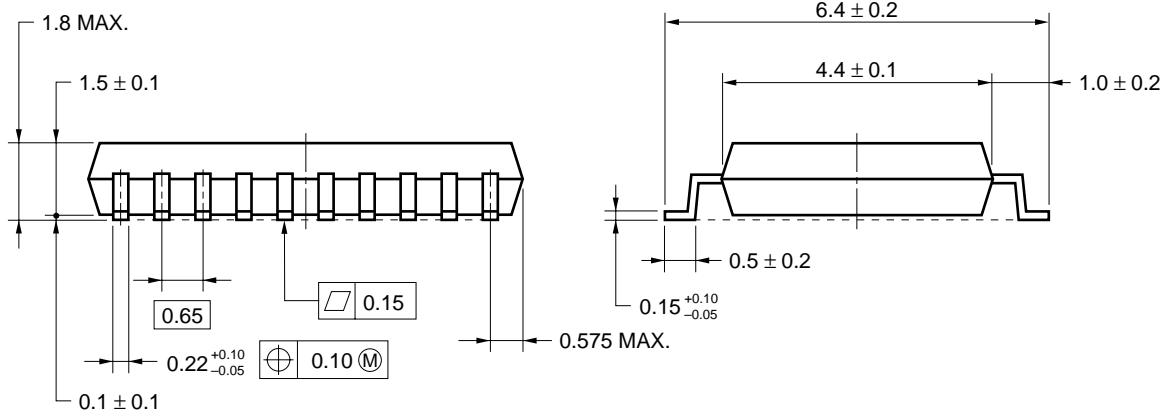
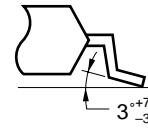
- \*1) ○ shows through holes
- \*2) ▨ pattern should be removed on this application
- \*3) ▩ shows short circuited strip for ground

PACKAGE DIMENSIONS

★ 20 PIN PLASTIC SSOP (225 mil) (UNIT: mm)



detail of lead end



**NOTE** Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

**RECOMMENDED SOLDERING CONDITIONS**

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales officers in case other soldering process is used or in case soldering is done under different conditions.

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

**μPC8116GR**

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 3, Exposure limit <sup>Note</sup> : None	IR35-00-3
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 3, Exposure limit <sup>Note</sup> : None	VP15-00-3
Wave soldering	Solder temperature: 260 °C or below, Reflow time: 10 seconds or below, Number of reflow process: 1, Exposure limit <sup>Note</sup> : None	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 3 seconds or below, Exposure limit <sup>Note</sup> : None	

**Note** Exposure limit before soldering after dry-pack package is opened.  
Storage conditions: 25 °C and relative humidity at 65 % or less.

**Caution** Do not apply more than single process at once, except for "Partial heating method".

[MEMO]

[MEMO]

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